

Formation of large area Al contacts on 6H- and 4H-SiC substrates

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Thermopower measurements in 4H-SiC and Theoretical calculations considering the phonon drag effect

Grivickas, V.; Stölzer, M.; **Velmre, Enn; Udal, Andres**; Grivickas, P.; Syväjärvi, M.; Yakimova, R.; Bikbajevs, V. Abstracts of the 3rd European Conference on Silicon Carbide and Related Materials : ECSCRM'2000 : Sept. 3-7, 2000, Kloster Banz, Germany 2000 / p. 144